Pt. 98, Subpt. I, Table I-5

Fable I−5 to Subpart I of Part 98—Default Emission Factors (1-U_{ii}) for Gas Utilization

Table I–5 to Subpart I of Part 98—Default Emission Factors $(1-U_{ij})$ for Gas Utilization Rates (U_{ij}) and By-Product Formation Rates (B_{ijk}) for MEMS Manufacturing

0.4 0 0 Notes: NA = Not applicable; i.e., there are no applicable default emission factor measurements for this NA 0.1 0. CF4 C2F6 CHF3 CH2F2 C3F8 c-C4F8 Remote NF3 SF6 C4F6a NA $_{A}^{N}$ NA Rates (Uij) and By-Product Formation Rates (Bijk) for MEMS Manufacturing NA NA NA NA 0.2 $^{2}0.1$ $^{2}0.02$ Process gas i 0.02 NA NA 0.1 0 NA 0.1 0.4 NA $_{\rm A}^{\rm N}$ $_{\rm AA}$ $_{\rm AA}$ NA NA9.0 CVD Chamber Cleaning BC₃F₈ NA NA 0.1 NA 0.9 CVD Chamber Cleaning BCF₄ CVD Chamber Cleaning 1–U_i Process type factors

¹ Estimate includes multi-gas etch processes.
² Estimate reflects presence of low-k, carbide and multi-gas etch processes that may contain a C-containing fluorinated GHG additive.

gas. This does not necessarily imply that a particular gas is not used in or emitted from a particular

process sub-type or process type.

[75 FR 74818, Dec. 1, 2010, as amended at 78 FR 68225, Nov. 13, 2013]